

LIST OF JOURNAL PAPERS 2013

- 1 - Altet, J., Gomez, D., Perpiñá, X., Mateo, D., González, J.L., Vellvehí, M., Jordà, X.
" EFFICIENCY DETERMINATION OF RF LINEAR POWER AMPLIFIERS BY STEADY-STATE
TEMPERATURE MONITORING USING BUILT-IN SENSORS "
SENSORS AND ACTUATORS A-PHYSICAL. Vol.192 49-57, 2013.
- 2 - Fernández-Martínez, P., Palomo, F.R., Hidalgo, S., Fleta, C., Campabadal, F., Flores, D.
" ANALYSIS OF DISPLACEMENT DAMAGE EFFECTS ON MOS CAPACITORS "
**NUCLEAR INSTRUMENTS METHODS IN PHYSICS RESEARCH SECTION A ACCELERATORS
SPECTROMETERS DETECTORS AND ASSOCIATED EQUIPMENT.** Proceedings of the 9th
International Conference on Radiation Effects on Semiconductor Materials Detectors and
Devices – October 9-12 2012 Dipartimento di Fisica e Astronomia - Sezione di Astronomia e
Scienza dello Spazio - Largo Enrico Fermi, 2, 50125 Firenze Organized by : Università degli Studi
di Firenze with the support of Istituto Nazionale di Fisica Nucleare. Vol.730 91-94, 2013.
- 3 - Fontserè, A., Pérez-Tomàs, A., Placidi, M., Baron, N., Chenot, S., Moreno, J.C., Cordier, Y.
" BULK TEMPERATURE IMPACT ON THE ALGAN/GAN HEMT FORWARD CURRENT ON SI, SAPPHIRE
AND FREE-STANDING GAN "
ECS SOLID STATE LETTERS. Vol.2 nº (1), P4-P7, 2013.
- 4 - Fontserè, A., Pérez-Tomàs, A., Placidi, M., Baron, N., Chenot, S., Moreno, J.C., Rennesson, S., Cordier, Y.
" MOLECULAR BEAM EPITAXIAL ALGAN/GAN HIGH ELECTRON MOBILITY TRANSISTORS
LEAKAGE THERMAL ACTIVATION ON SILICON AND SAPPHIRE "
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- 5 - Gammon, P.M., Pérez-Tomàs, A., Shah, V.A., Vavasour, O., Donchev, E., Pang, J.S., Myronov, M.,
Fisher, C.A., Jennings, M.R., Leadley, D.R., Mawby, P.A.
" MODELLING THE INHOMOGENEOUS SIC SCHOTTKY INTERFACE "
JOURNAL OF APPLIED PHYSICS. Vol.114 nº (2), 223704, 2013.
- 6 - Gonzalez-Guerrero, M.J., Esquivel, J.P., Sánchez-Molas, D., Godignon, P., Munoz, F.X., Del Campo, F.J.,
Giroud, F., Minteer, S.D., Sabaté, N.
" MEMBRANELESS GLUCOSE/O₂ MICROFLUIDIC ENZYMATIC BIOFUEL CELL USING PYROLYZED
PHOTORESIST FILM ELECTRODES "
LAB ON A CHIP. Vol.13 nº (15), 2972-2979, 2013.
- 7 - Jakovenko, J., Formanek, J., Perpiñá, X., Jordà, X., Vellvehí, M., Werkhoven, R., Husak, M., Kunen, J.,
Bancken, P., Bolt, P.J., Gasse, A.
" DESIGN METHODOLOGIES FOR RELIABILITY OF SSL LED BOARDS "
MICROELECTRONICS RELIABILITY. Vol.53 nº (8), 1076-1083, 2013.
- 8 - León, J., Perpiñá, X., Altet, J., Vellvehí, M., Jordà, X.
" PHYSICALLY BASED ANALYSIS OF ELECTRICAL FREQUENCY RESPONSE OF PASSIVE
MICROELECTRONIC CIRCUITS BY HETERODYNE LOCK-IN THERMAL MEANS "
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- 9 - León, J., Perpiñá, X., Altet, J., Vellvehí, M., Jordà, X.
" SPATIALLY AND FREQUENCY-RESOLVED MONITORING OF INTRADIE CAPACITIVE COUPLING

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10 - León, J., Perpiñá, X., Vellvehí, M., Baldi, A., Sacristán, J., Jordà, X.
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11 - Martín, I., Gabriel, G., Guimerà, A., Palomer, X., Reig, R., Sánchez-Vives, M., Villa, R., Godignon, P.
" MULTI-WALLED CARBON NANOTUBE BASED MULTI-ELECTRODE ARRAYS FOR THE DETECTION
OF THE EMERGENT ACTIVITY IN THE CORTICAL NETWORK "
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" THERMAL BEHAVIOR OF SIC POWER DIODES "
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13 - Pardo, b., Gasse, A., Fargeix, A., Jakovenko, J., Werkhoven, R., Perpiñá, X., Jordà, X., Vellvehí, M.,
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14 - Pérez-Tomàs, A., Fontserè, A., Sánchez, S., Jennings, M.R., Gammon, P.M., Cordier, Y.
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15 - Pérez-Tomàs, A., Fontserè, A., Placidi, M., Jennings, M.R., Gammon, P.M.
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CONTACTS TO GAN AND SIC "
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16 - Perpiñá, X., Cortés, I., Arresti, J., Jordà, X., Rebollo, J.
" LAYOUT ROLE IN FAILURE PHYSICS OF IGBTs UNDER OVERLOADING CLAMPED INDUCTIVE
TURNOFF "
IEEE TRANSACTIONS ON ELECTRON DEVICES. Vol.60 nº (2), 598-605, 2013.

17 - Sánchez-Molas, D., Cases-Utrera, J., Godignon, P., Del Campo, F.J.
" MERCURY DETECTION AT MICROFABRICATED PYROLYZED PHOTORESIST FILM (PPF) DISK
ELECTRODES "
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